Features

- Split Gate Trench MOSFET Technology
- Moisture Sensitivity Level 1
- Halogen Free."Green" Device(Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant (Note2)("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-CHANNEL MOSFET

Maximum Ratings

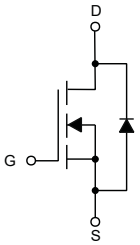
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 40°C/W Junction to Ambient (Note3)
- Thermal Resistance: 0.95°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Volltage		V_{GS}	±20	V
Continuous Drain Current	T_C=25°C	I_D	150	A
	T_C=100°C		106	
Pulsed Drain Current (Note 4)		I_{DM}	600	A
Total Power Dissipation(Note 5)		P_D	158	W
Single Pulsed Avalanche Energy(Note 6)		E_{AS}	242	mJ

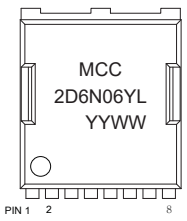
Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. High Temperature Solder Exemption Applied, see EU Directive Annex 7(a)-I.
3. The value of $R_{\theta JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
4. Repetitive rating; pulse width limited by max. junction temperature.
5. P_D is based on max. junction temperature, using junction-case thermal resistance.
6. T_J=25°C, V_{DD}=30V, V_{GS}=10V, R_G=25Ω, L=1mH.

Internal Structure and Marking Code

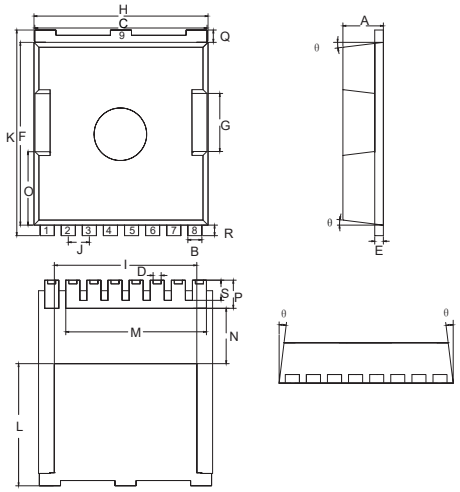


1. GATE
2,3,4,5,6,7,8. SOURCE
9. DRAIN



4 codes in total
YY is the year
WW is the week

TOLL-8L



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.087	0.094	2.20	2.40	
B	0.028	0.035	0.70	0.90	
C	0.382	0.390	9.70	9.90	
D	0.017	0.020	0.42	0.50	
E	0.016	0.024	0.40	0.60	
F	0.405	0.417	10.28	10.58	
G	0.122	0.138	3.10	3.50	
H	0.382	0.398	9.70	10.10	
I	0.311	0.327	7.90	8.30	
J	0.047		1.20		BSC
K	0.452	0.468	11.48	11.88	
L	0.266	0.281	6.75	7.15	
M	0.315		8.00		
N	0.118	0.130	3.00	3.30	
O	0.157	0.172	3.98	4.38	
P	0.055	0.071	1.40	1.80	
Q	0.024	0.031	0.60	0.80	
R	0.020	0.028	0.50	0.70	
S	0.039	0.051	1.00	1.30	
θ	4°	10°	4°	10°	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS}=0, I_D=250μA	60			V
Gate-Source Leakage Current	I_{GSS}	V_{DS}=0V, V_{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V, V_{GS}=0V			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	1.0	1.8	2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=75A		1.9	2.6	mΩ
		V_{GS}=4.5V, I_D=20A		2.8	4.0	
Gate Resistance	R_G	f=1 MHz, Open Drain		2.0		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				150	A
Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_S=75A			1.2	V
Reverse Recovery Time	t_{rr}	I_F=30A, dI_F/dt=100A/μs		41.8		ns
Reverse Recovery Charge	Q_{rr}			40.3		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	V_{DS}=30V,V_{GS}=0V,f=1MHz		3117		pF
Output Capacitance	C_{oss}			1481		
Reverse Transfer Capacitance	C_{rss}			88		
Total Gate Charge	Q_g	V_{DS}=30V,V_{GS}=10V,I_D=75A		55.5		nC
Gate-Source Charge	Q_{gs}			12		
Gate-Drain Charge	Q_{gd}			14.2		
Turn-On Delay Time	$t_{d(on)}$	V_{DD}=30V, V_{GS}=10V I_{DS}=75A,R_G=6Ω		14.4		ns
Turn-On Rise Time	t_r			169		
Turn-Off Delay Time	$t_{d(off)}$			60.8		
Turn-Off Fall Time	t_f			220		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

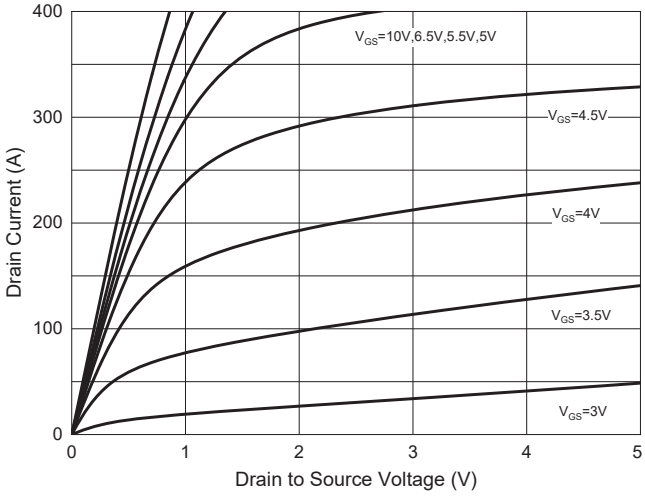


Fig. 2 - Transfer Characteristics

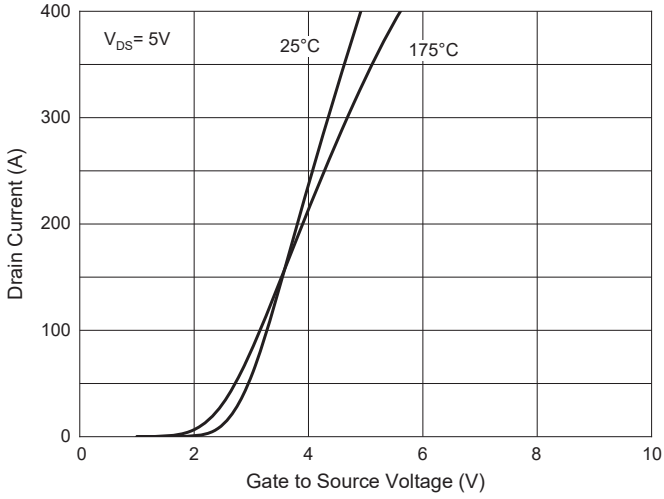


Fig. 3 - $R_{DS(ON)}$-V_{GS}

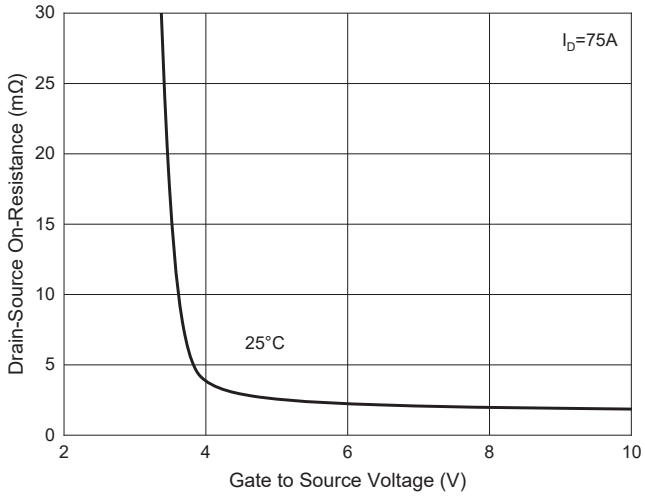


Fig. 4 - $R_{DS(ON)}$-I_D

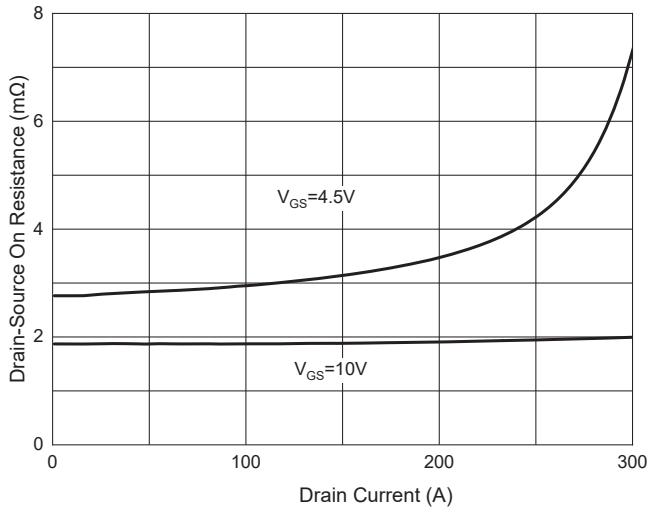


Fig. 5 - Capacitance Characteristics

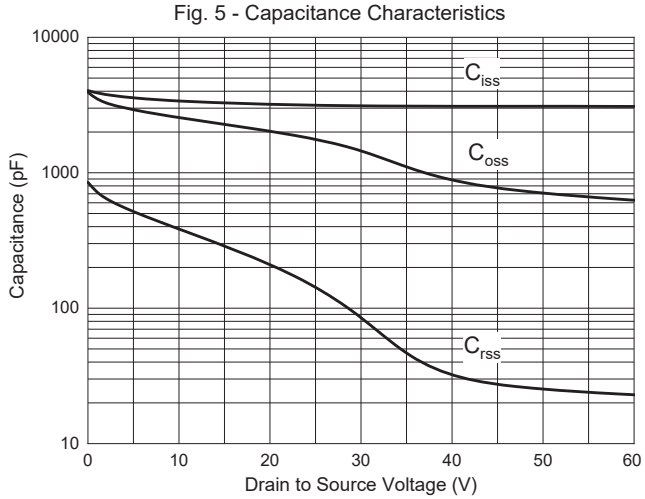
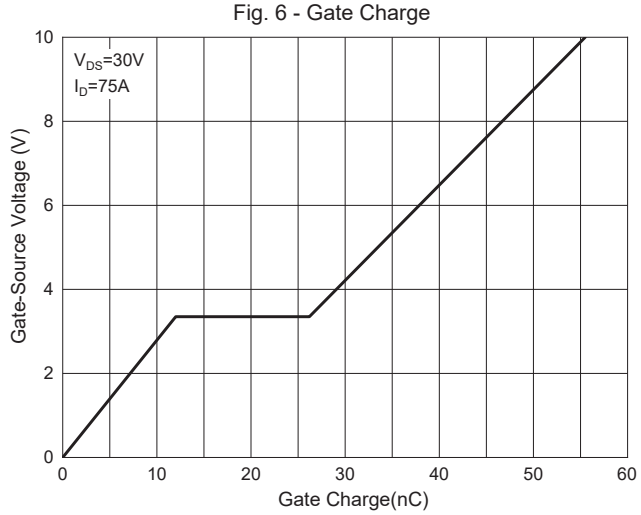


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold Voltage

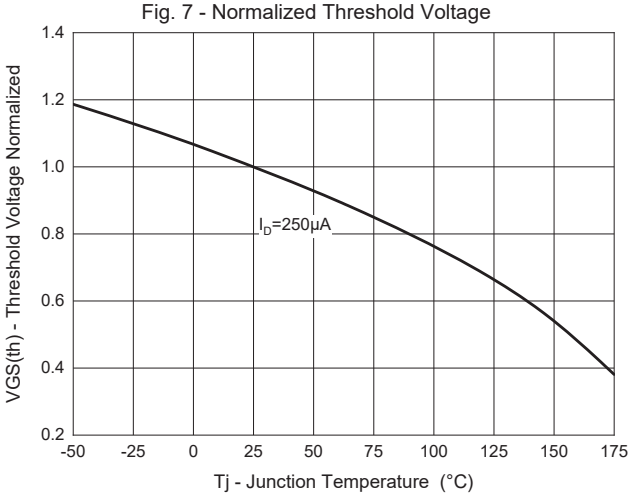


Fig. 8 - Normalized On Resistance Characteristics

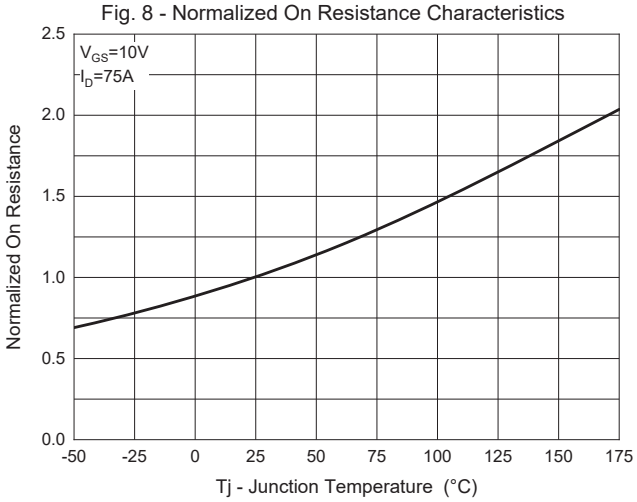


Fig. 9 - I_S-V_{SD}

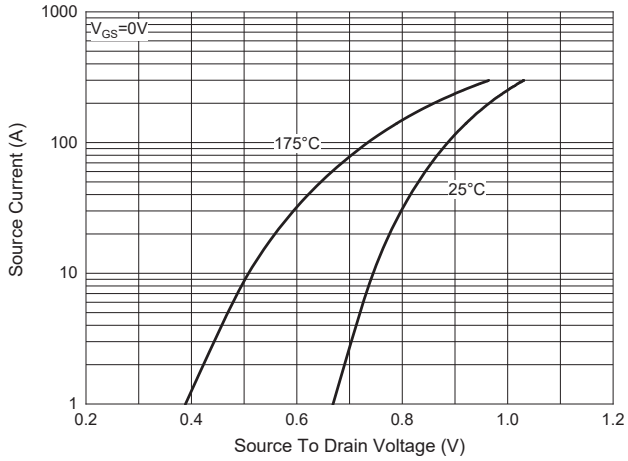


Fig. 10 - Drain Current

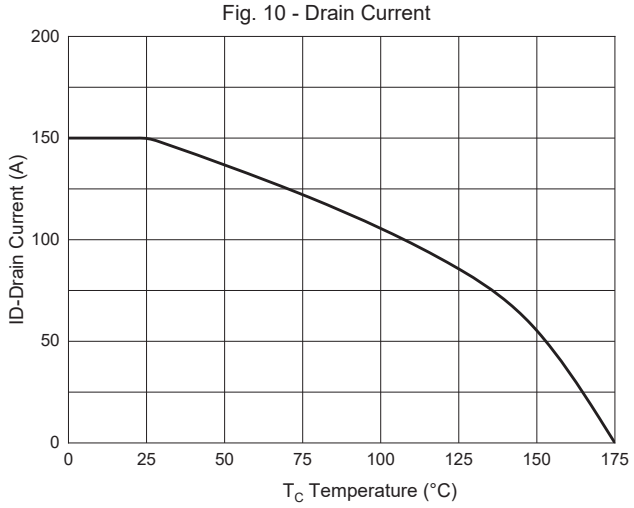
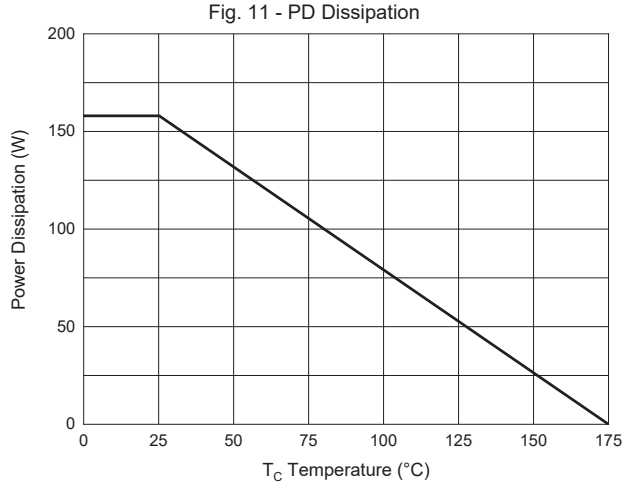


Fig. 11 - PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

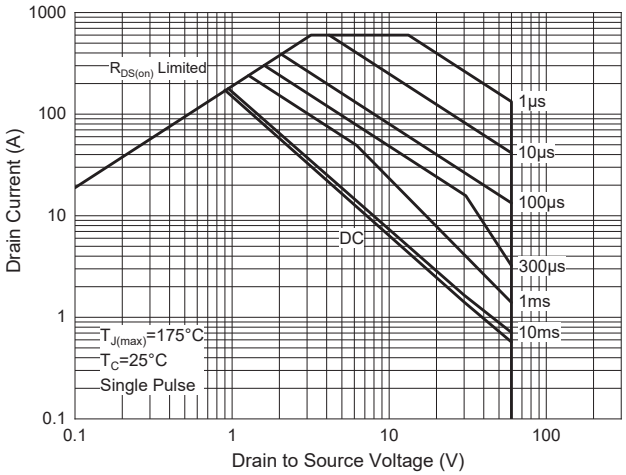
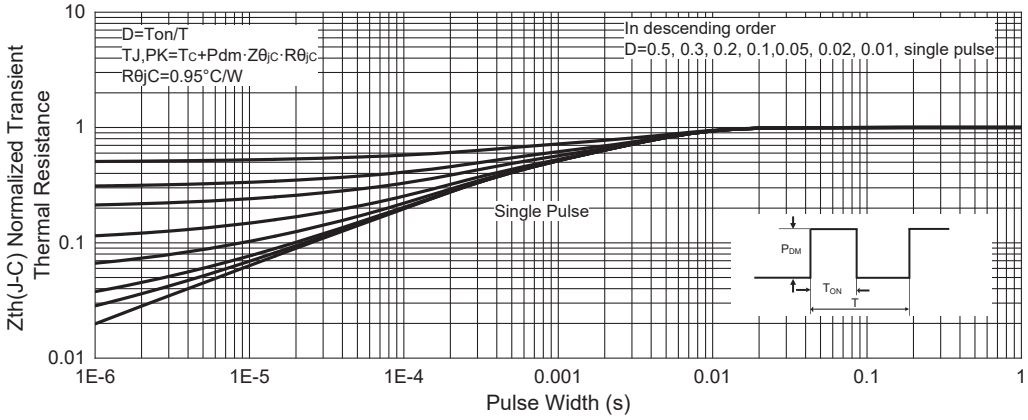


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2Kpcs/Reel

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